

12V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
-12V	14.8m Ω @ V _{GS} = -4.5V	-9.5A
	$19m\Omega @ V_{GS} = -2.5V$	-8.5A
	$26m\Omega @ V_{GS} = -1.8V$	-7.2A
	$32m\Omega @ V_{GS} = -1.5V$	-6.6A

Description

This MOSFET is designed specifically for use in battery management applications.

Features

- 0.6mm profile ideal for low profile applications
- PCB footprint of 4mm²
- Low Gate Threshold Voltage
- Fast Switching Speed
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4

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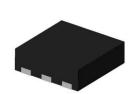
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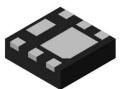
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Weight: 0.0065 grams (Approximate)

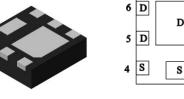


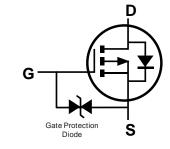


Top View



Bottom View





Pin Out **Bottom View**

Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP1022UFDF-7	U-DFN2020-6	3,000/Tape & Reel
DMP1022UFDF-13	U-DFN2020-6	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

U-DFN2020-6

Marking Information



PU = Product Type Marking Code YM = Date Code Marking Y = Year (ex: A = 2013)M = Month (ex: 9 = September)

Date Code Key

Year	2013	2014	20	15	2016	2017	2018	2019	20	20	2021	2022
Code	Α	В	()	D	Е	F	G	I	+	1	J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-12	V		
Gate-Source Voltage			V _{GSS}	±8	V
Continuos Durin Compant (Nata C) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-9.5 -7.6	А
Continuous Drain Current (Note 6) V _{GS} = -4.5V	t<5s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-11.0 -8.8	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-90	Α		
Continuous Source-Drain Diode Current	Is	-2.5 -7.1	А		
Pulsed Source-Drain Diode Current (10µs pulse, duty	I _{SM}	-50	Α		

Thermal Characteristics

Characteristic		Symbol	Value	Units	
Total Bower Dissination (Note 5)	$T_A = +25^{\circ}C$	C	0.73	W	
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	P_{D}	0.47		
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	6	172	°C/W	
memai Resistance, Junction to Ambient (Note 5)	t<5s	$R_{\theta JA}$	128		
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	C	2.1	W	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	P_{D}	1.3		
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	6	59		
Thermal Resistance, Junction to Ambient (Note 6)	t<5s	$R_{\theta JA}$	45	°C/W	
Thermal Resistance, Junction to Case (Note 6)	Steady state	$R_{\theta JC}$	5.1		
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

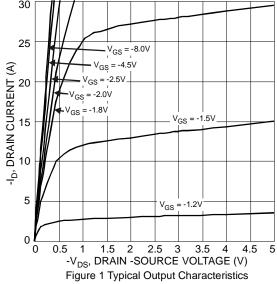
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-12	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	-200	nA	$V_{DS} = -12V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current T _J = +55°C (Note 8)	I _{DSS}	_	_	-2	μA	$V_{DS} = -12V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 8V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-0.35	_	-0.8	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
			12	14.8		$V_{GS} = -4.5V, I_D = -4A$	
Static Drain-Source On-Resistance	D		15	19	mΩ	$V_{GS} = -2.5V, I_D = -4A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	20	26		$V_{GS} = -1.8V, I_D = -4A$	
			23	32		$V_{GS} = -1.5V, I_D = -2A$	
Diode Forward Voltage	V_{SD}	_	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -8A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	2,712	_		101/1/	
Output Capacitance	Coss	_	514	_	pF	$V_{DS} = -10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	467	_		1 – 1.01/11/12	
Gate Resistance	R_g	_	8.6	18	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	48.3	_		$V_{GS} = -8V, V_{DS} = -6V, I_{D} = -10A$	
Total Gate Charge	Qg	_	28.6	_	nC	V 45V V 6V	
Gate-Source Charge	Q _{gs}	_	4.2	_	l IIC	$V_{GS} = -4.5V, V_{DS} = -6V,$ $I_{D} = -10A$	
Gate-Drain Charge	Q_{gd}	_	7.0	_		ID = -10A	
Turn-On Delay Time	t _{D(on)}	_	25.1	_			
Turn-On Rise Time	t _r	_	39.8	_		$V_{DS} = -6V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t _{D(off)}	_	141	_	ns	$R_G = 1\Omega$, $I_D = -8A$	
Turn-Off Fall Time	t _f	_	147	_			

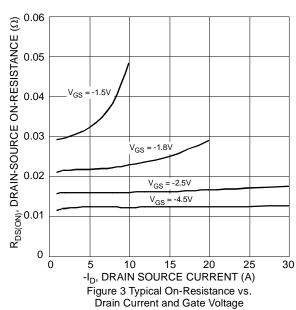
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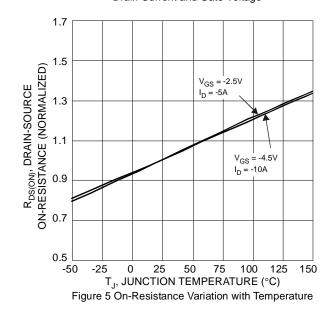
- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

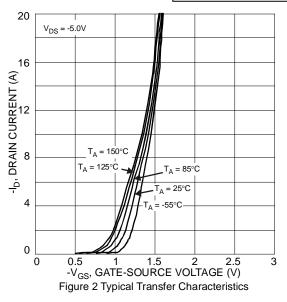


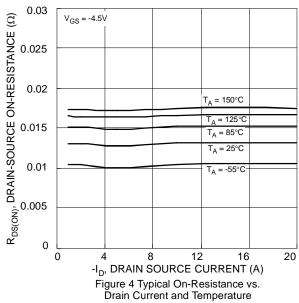












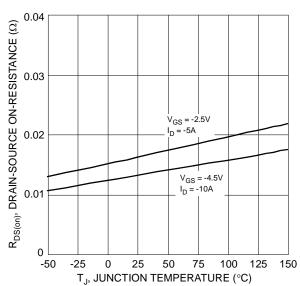
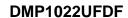


Figure 6 On-Resistance Variation with Temperature





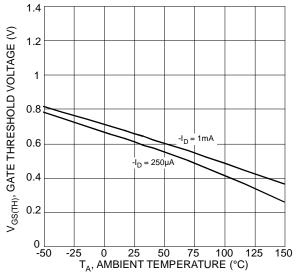
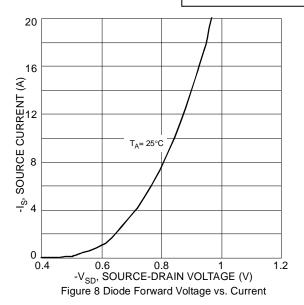
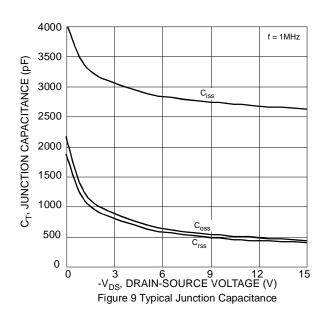
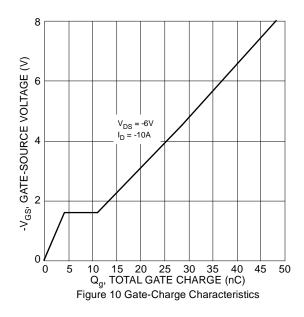
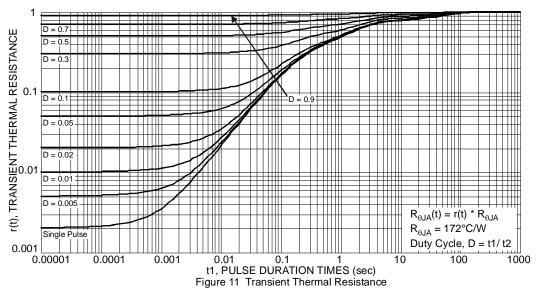


Figure 7 Gate Threshold Variation vs. Ambient Temperature





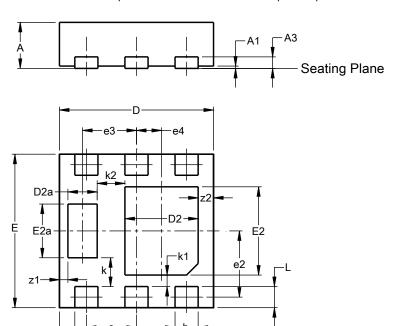






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

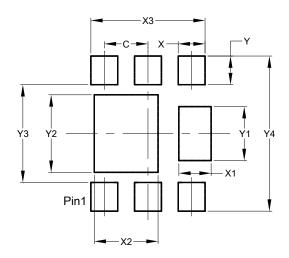


U-DFN2020-6							
(Type F)							
Dim	Min	Min Max Typ					
Α	0.57	0.63	0.60				
A1	0.00	0.05	0.03				
A3	-	-	0.15				
b	0.25	0.35	0.30				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
D2a	0.33	0.43	0.38				
Е	1.95	2.05	2.00				
E2	1.05	1.25	1.15				
E2a	0.65	0.75	0.70				
е		0.65 BSC					
e2		0.863 BSC					
е3		0.70 BSC					
e4		0.325 BSC					
k	0.37 BSC						
k1	0.15 BSC						
k2	0.36 BSC						
L	0.225 0.325 0.275						
Z	0.20 BSC						
z1	0.110 BSC						
z2	0.20 BSC						
All C	All Dimensions in mm						

Suggested Pad Layout

z(4x)

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value				
Dilliensions	(in mm)				
С	0.650				
Х	0.400				
X1	0.480				
X2	0.950				
Х3	1.700				
Υ	0.425				
Y1	0.800				
Y2	1.150				
Y3	1.450				
Y4	2.300				



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